#### MTM763200LBF

## **Panasonic**

### MTM763200LBF

Silicon N-channel MOSFET (FET1) Silicon P-channel MOSFET (FET2)

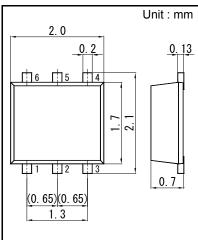
For Switching For DC-DC Converter

#### ■ Features

- Low Drain-source On-state Resistance : RDS(on)typ. N-ch = 80 mΩ(VGS = 4.0 V) P-ch:100 mΩ (VGS = -4.0 V)
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL : Level 1 compliant)
- Marking Symbol JB
- Basic Part Number Nch+Pch MOS 20V (Individual)

#### ■ Packaging

Embossed type (Thermo-compression sealing) 3 000 pcs / reel (standard)



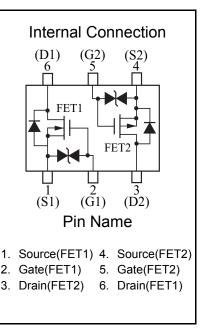
- 1. Source(FET1) 4. Source(FET2)
- 2. Gate(FET1) 5. Gate(FET2)
- 3. Drain(FET2) 6. Drain(FET1)

Panasonic	WSMini6-F1-B
JEITA	SC-113DA
Code	_

#### ■ Absolute Maximum Ratings Ta = 25 °C

Parameter		Symbol	Rating	Unit
	Drain-source Voltage	VDS	20	V
	Gate-source Voltage	VGS	±10	V
	Drain current	ID	1.9	Α
	Peak drain current	IDp	12	Α
	Drain-source Voltage	VDS	-20	V
FET2	Gate-source Voltage	VGS	±10	V
(P-ch.)	Drain current	ID	-1.2	Α
	Peak drain current	IDp	-7	Α
	Total power dissipation *1	PD	700	mW
	Channel temperature	Tch	150	°C
	Operating ambient temperature	Topr	-40 to +85	°C
	Storage Temperature Range	Tstg	-55 to +150	°C

Note \*1 Measuring on ceramic substrate at 40 mm  $\cdot$  38 mm  $\cdot$  0.2 mm. PD absolute maximum rating Non-heat sink: 150 mW.



#### MTM763200LBF

## **Panasonic**

#### ■ Electrical Characteristics Ta = 25 °C ± 3 °C

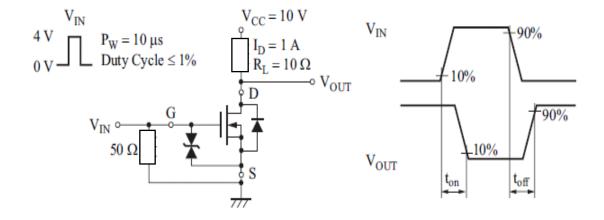
FET1 (N-ch.)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit	
Drain-source Breakdown Voltage	VDSS	ID = 1.0 mA, VGS = 0 V	20			V	
Zero Gate Voltage Drain Current	IDSS	VDS = 20 V, VGS = 0 V			1.0	μΑ	
Gate-source Leakage Current	IGSS	$VGS = \pm 8.0 \text{ V}, VDS = 0 \text{ V}$			±10	μA	
Gate-source Threshold Voltage	Vth	ID = 1.0 mA, VDS = 10 V	0.4	0.85	1.3	V	
Drain-source ON resistance *1	RDS(ON)1	ID = 1.0 A, VGS = 4.0 V		80	105	m()	
	RDS(ON)2	ID = 0.5 A, VGS = 2.5 V		100	150	mΩ	
Forward transfer admittance *1	Yfs	ID = 1.0 A, VDS = 10 V	3.0			S	
Input Capacitance	Ciss			280			
Output Capacitance	Coss	VDS = 10 V, VGS = 0, f = 1 MHz		18		pF	
Reverse Transfer Capacitance	Crss			17			
Turn-on time *2	ton	VDD = 10 V, VGS = 0 to 4 V,		12			
rum-on time		ID = 1.0 A		12		ns	
Turn-off time *2	toff	VDD = 10 V, VGS = 4 to 0 V,		50			
		ID = 1.0 A		50			

Note: 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

2. \*1 Pulse measurement

#### \*2 Measurement circuit for Turn-on Time / Turn-off Time



Doc No. TT4-EA-10567

**Panasonic** 

Revision. 2

MOS FET

#### MTM763200LBF

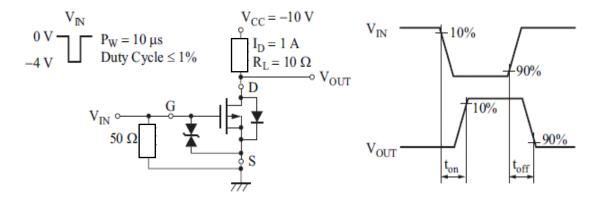
FET2 (P-ch.)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Drain-source Breakdown Voltage	VDSS	ID = -1 mA, VGS = 0 V	-20			V
Zero Gate Voltage Drain Current	IDSS	VDS = -20 V, VGS = 0 V			-1.0	μA
Gate-source Leakage Current	IGSS	$VGS = \pm 8 \text{ V}, VDS = 0 \text{ V}$			±10	μA
Gate-source Threshold Voltage	Vth	ID = -1.0 mA, VDS = -10 V	-0.4	-0.85	-1.3	V
Drain-source On-state Resistance *1	RDS(ON)1	ID = -1.0 A, VGS = -4.0 V		100	130	mO.
	RDS(ON)2	ID = -0.6 A, VGS = -2.5 V		130	200	mΩ
Forward transfer admittance *1	Yfs	ID = -1.0 A, VDS = -10 V	3.0			S
Input Capacitance	Ciss			440		
Output Capacitance	Coss	VDS = -10 V, VGS = 0, f = 1 MHz		40		pF
Reverse Transfer Capacitance	Crss			38		
Turn-on Time *2	ton	VDD = -10 V, VGS = 0 to -4 V		35		,
		ID = -1 A		33		ne
Turn-off Time *2	toff	VDD = -10 V, VGS = -4 to 0 V		100		ns
rum-on rime		ID = -1 A		100		

Note: 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

2. \*1 Pulse measurement

\*2 Measurement circuit for Turn-on Time / Turn-off Time



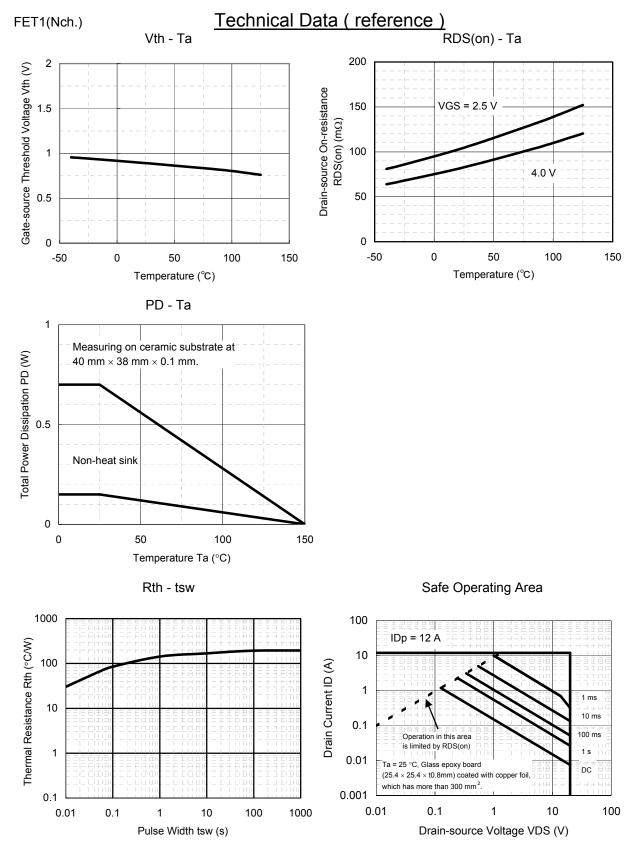
### MTM763200LBF



Technical Data (reference) FET1(Nch.) ID - VDS ID - VGS 1.5 1.5 VGS = 4.0 V Drain Current ID (A) Drain current ID (A) 9.0 2.0 V Ta = 85 °C 25 ℃ 1.5 V - 40 °C 0 0 0.1 0.2 0.3 0 0.5 2 1.5 Drain-source Voltage VDS (V) Gate-source voltage VGS (V) VDS - VGS RDS(on) - ID 1000 0.6 Drain-source On-state Resistance RDS(on) (mΩ) Drain-source Voltage VDS (V) 0.5 0.4 0.5 A 2.5 V 0.3 ID = 1.0 A VGS = 4.0 V 0.2 0.1 0 10 2 0 3 0.1 6 Drain Current ID (A) Gate-source Voltage VGS (V) Capacitance - VDS 1000 Ciss

#### MTM763200LBF

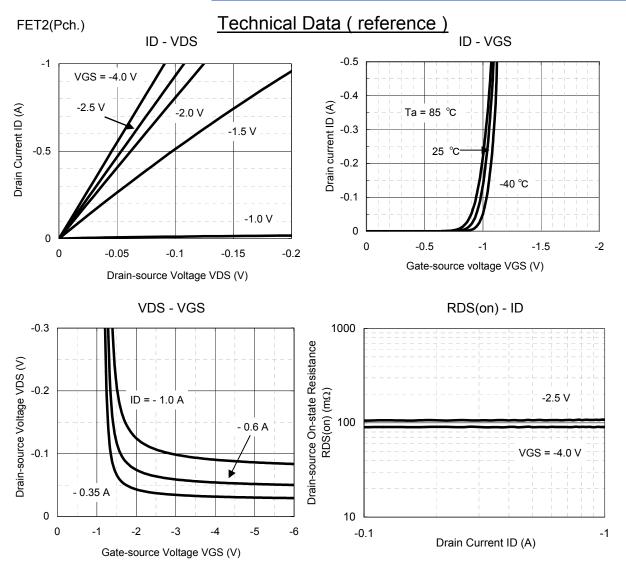
## **Panasonic**



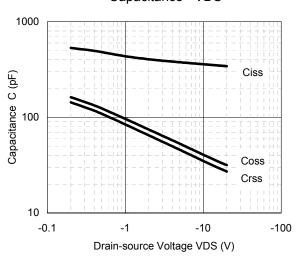
Page 5 of 8

### MTM763200LBF

## **Panasonic**

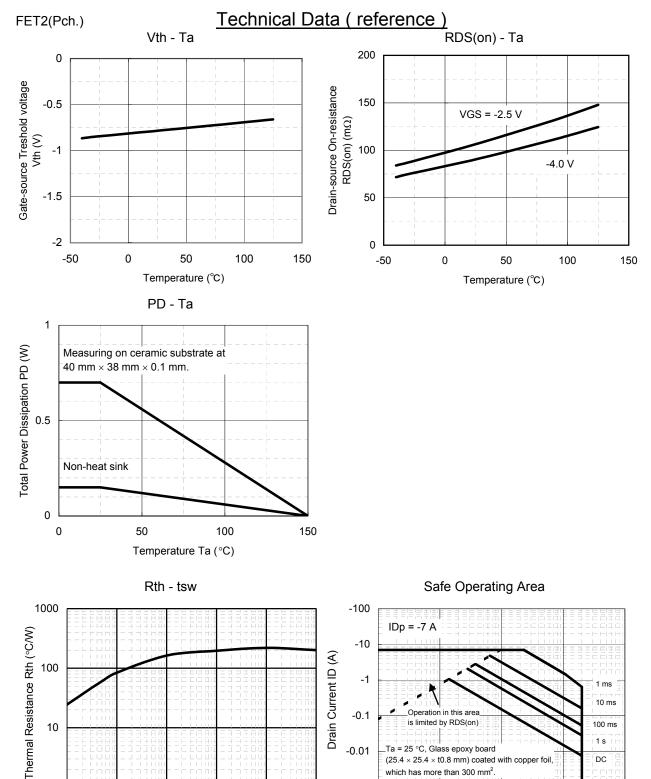


Capacitance - VDS



### MTM763200LBF





Page 7 of 8

DC

-100

(25.4  $\times$  25.4  $\times$  t0.8 mm) coated with copper foil

Drain-source Voltage VDS (V)

which has more than 300 mm<sup>2</sup>

-0.1

-0.001

1000

-0.01

Established: 2008-03-07 Revised

0.01

0.1

10

Pulse Width tsw (s)

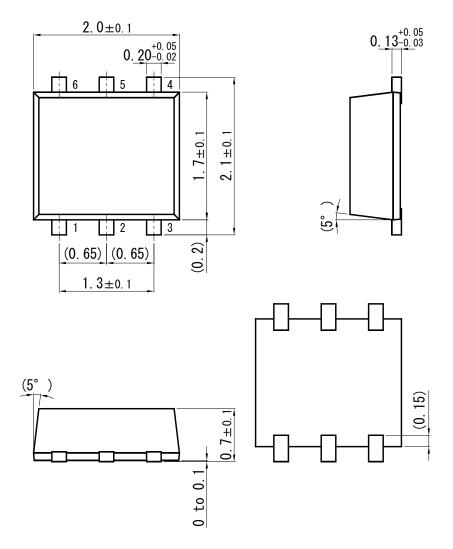
100

### MTM763200LBF

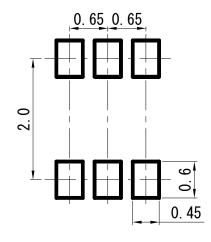
## WSMini6-F1-B

**Panasonic** 

Unit: mm



#### ■ Land Pattern (Reference) (Unit: mm)



# Request for your special attention and precautions in using the technical information and semiconductors described in this book

- (1) If any of the products or technical information described in this book is to be exported or provided to non-residents, the laws and regulations of the exporting country, especially, those with regard to security export control, must be observed.
- (2) The technical information described in this book is intended only to show the main characteristics and application circuit examples of the products. No license is granted in and to any intellectual property right or other right owned by Panasonic Corporation or any other company. Therefore, no responsibility is assumed by our company as to the infringement upon any such right owned by any other company which may arise as a result of the use of technical information de-scribed in this book.
- (3) The products described in this book are intended to be used for general applications (such as office equipment, communications equipment, measuring instruments and household appliances), or for specific applications as expressly stated in this book.
  - Please consult with our sales staff in advance for information on the following applications, moreover please exchange documents separately on terms of use etc.: Special applications (such as for in-vehicle equipment, airplanes, aerospace, automotive equipment, traffic signaling equipment, combustion equipment, medical equipment and safety devices) in which exceptional quality and reliability are required, or if the failure or malfunction of the products may directly jeopardize life or harm the human body.
  - Unless exchanging documents on terms of use etc. in advance, it is to be understood that our company shall not be held responsible for any damage incurred as a result of or in connection with your using the products described in this book for any special application.
- (4) The products and product specifications described in this book are subject to change without notice for modification and/or improvement. At the final stage of your design, purchasing, or use of the products, therefore, ask for the most upto-date Product Standards in advance to make sure that the latest specifications satisfy your requirements.
- (5) When designing your equipment, comply with the range of absolute maximum rating and the guaranteed operating conditions (operating power supply voltage and operating environment etc.). Especially, please be careful not to exceed the range of absolute maximum rating on the transient state, such as power-on, power-off and mode-switching. Otherwise, we will not be liable for any defect which may arise later in your equipment.
  Even when the products are used within the guaranteed values, take into the consideration of incidence of break down and failure mode, possible to occur to semiconductor products. Measures on the systems such as redundant design, arresting the spread of fire or preventing glitch are recommended in order to prevent physical injury, fire, social damages, for example, by using the products.
- (6) Comply with the instructions for use in order to prevent breakdown and characteristics change due to external factors (ESD, EOS, thermal stress and mechanical stress) at the time of handling, mounting or at customer's process. We do not guarantee quality for disassembled products or the product re-mounted after removing from the mounting board. When using products for which damp-proof packing is required, satisfy the conditions, such as shelf life and the elapsed time since first opening the packages.
- (7) When reselling products described in this book to other companies without our permission and receiving any claim of request from the resale destination, please understand that customers will bear the burden.
- (8) This book may be not reprinted or reproduced whether wholly or partially, without the prior written permission of our company.